> 500 MHz, - 3 dB Bandwidth; Dual SPDT Analog Switch

DESCRIPTION

DG2721 is a low R_{on}, high bandwidth analog switch configured in dual SPDT.

It achieves 5.7 Ω switch on resistance, greater than 500 MHz - 3 dB bandwidth with 5 pF load, and a channel to channel crosstalk and Isolation at - 49 dB.

Fabricated with high density sub micro CMOS process, the DG2721 provides low parasitic capacitance, handles bidirectional signal flow with minimized phase distortion. Guaranteed 1.3 V logic high threshold makes it possible to interface directly with low voltage MCUs.

The DG2721 is designed for a wide range of operating voltages from 2.7 V to 4.3 V that can be driven directly from one cell Li-ion battery. On-chip protection circuit protects again fault events when signals at “com” pins goes beyond V+.

Latch up current is greater than 300 mA, as per JESD78, and its ESD tolerance exceeds 8 kV.

Packaged in ultra small miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm), it is ideal for portable high speed mix signal switching application.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL rating.

As a further sign of Vishay Siliconix's commitment, the DG2721 is fully RoHS complaint.

FEATURES

- Wide operation voltage range
- Low on-resistance, 5.7 Ω (typical at 3 V)
- Low capacitance, 5.6 pF (typical)
- - 3 dB high bandwidth with 5 pF load: > 500 MHz (typical)
- Low bit to bit skew: 40 pS (typical)
- Low power consumption
- Low logic threshold: V
- Power down protection: COM_1 and COM_2 pins can tolerate up to 5 V when V+ = 0 V
- Logic (IN_1 and IN_2) above V+ tolerance
- Latch-up current greater than 300 mA per JESD78
- 8 kV ESD protection (HBM)
- Lead (Pb)-free low profile miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm)

Pb-free

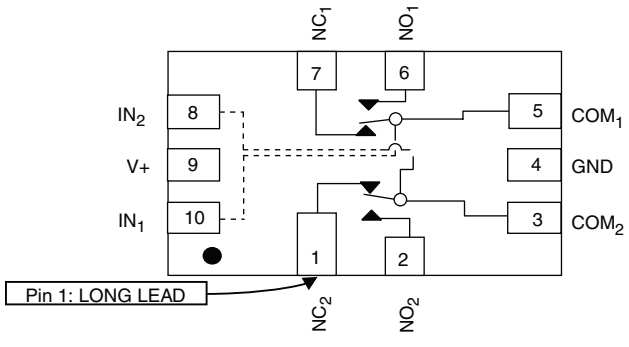
RoHS
COMPLIANT

APPLICATIONS

- Cellular phones
- Portable media players
- PDA
- Digital camera
- GPS
- Notebook computer
- TV, monitor, and set top box
- Radio

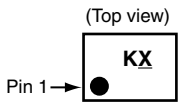
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

miniQFN-10L



Top View

Device Marking: K<u>X</u> for DG2721
<u>X</u> = Date/Lot Traceability Code



ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	miniQFN-10	DG2721DN-T1-E4

TRUTH TABLE

IN_1 (Pin 10)	IN_2 (Pin 8)	Function
X	0	$COM2 = NC_2$
X	1	$COM2 = NO_2$
0	X	$COM1 = NC_1$
1	X	$COM1 = NO_1$

PIN DESCRIPTIONS

Pin Name	Description
IN_1	Select Input COM_1
IN_2	Select Input COM_2
$NC_{1/2}$, $NO_{1/2}$, $COM_{1/2}$	Data Channel

ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted

Parameter		Limit	Unit
Reference to GND	V+	- 0.3 to 5.0	V
	IN_X, NC_X, NO_X, COM_X[a]	- 0.3 to (V+ + 0.3)	
Current (Any Terminal except IN_X, NC_X, NO_X, COM_X)		30	mA
Continuous Current (IN_X, NC_X, NO_X, COM_X)		± 250	
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 500	
Storage Temperature (D Suffix)		- 65 to 150	°C
Power Dissipation (Packages)[b]	miniQFN-10[c]	208	mW
ESD (Human Body Model) All Pins I/O to GND		 4 8	kV
Latch-up (Current Injection)		350	mA

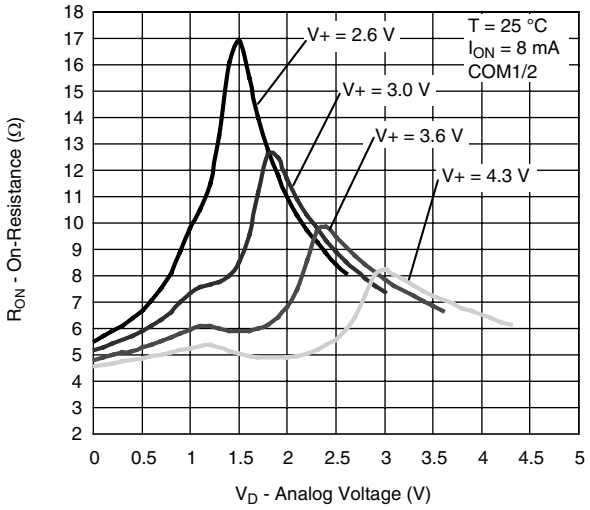
Notes:
a. Signals on IN_X, NC_X, NO_X, COM_X exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 2.6 mW/°C above 70 °C.

SPECIFICATIONS V+ = 3.0 V							
				Limits - 40 °C to 85 °C			
Parameter	**Symbol**	**Test Conditions Otherwise Unless Specified**	**Temp.[a]**	**Min.[b]**	**Typ.[c]**	**Max.[b]**	**Unit**
Analog Switch							
Analog Signal Range[d]	V_{ANALOG}	$r_{DS(on)}$	Full	0		V+	V
On-Resistance	$R_{DS(on)}$	V+ = 3.0 V, I_{COM} = 8 mA, $V_{NC/NO}$ = 0.4 V	Room		5.7	7	Ω
			Full			9	
On-Resistance Match[d]	ΔR_{ON}	V+ = 3.0 V, I_{COM} = 8 mA, $V_{NC/NO}$ = 0.4 V	Room		0.35		
On-Resistance Resistance Flatness[d]	R_{ON} Flatness	V+ = 3.0 V, I_{COM} = 8 mA, $V_{NC/NO}$ = 0.0 V, 1.0 V	Room		2		
Switch Off Leakage Current	$I_{(off)}$	V+ = 4.3 V, $V_{NC/NO}$ = 0.3 V, 3.0 V, V_{COM} = 3.0 V, 0.3 V	Full	- 100		100	nA
Channel On Leakage Current	$I_{(on)}$	V+ = 4.3 V, $V_{NC/NO}$ = 0.3 V, 4.0 V, V_{COM} = 4.0 V, 0.3 V	Full	- 200		200	
Digital Control							
Input Voltage High	V_{INH}	V+ = 3.0 V to 3.6 V	Full	1.3			V
		V+ = 4.3 V	Full	1.7			
Input Voltage Low	V_{INL}	V+ = 3.0 V to 4.3 V	Full			0.5	
Input Capacitance	C_{IN}		Full		5.6		pF
Input Current	I_{INL} or I_{INH}	V_{IN} = 0 or V+	Full	- 1		1	µA
Dynamic Characteristics							
Break-Before-Make Time[e, d]	t_{BBM}	V+ = 3.0 V, V_{COM} = 1.5 V, R_L = 50 Ω, C_L = 35 pF	Room		5		ns
			Full				
Turn-On Time[e, d]	t_{ON}		Room			30	
			Full				
Turn-Off Time[e, d]	t_{OFF}		Room			25	
			Full				
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, R_{GEN} = 0 Ω, V_{GEN} = 0 V	Room		0.5		pC
Off-Isolation[d]	OIRR	V+ = 3.0 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF, f = 240 MHz			- 30		dB
Crosstalk[d]	X_{TALK}				- 49		
Bandwidth[d]	BW	V+ = 3.0 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF, - 3 dB			> 500		MHz
Channel-Off Capacitance[d]	$C_{NO(off)}$	V+ = 3.3 V, f = 1 MHz			4		pF
	$C_{NC(off)}$				4		
Channel-On Capacitance[d]	$C_{COM(on)}$				11		
Channel-to-Channel Skew[d]	$t_{SK(O)}$	V+ = 3.0 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF			50		ps
Skew Off Opposite Transitions of the Same Output[d]	$t_{SK(p)}$				20		
Total Jitter[d]	t_J				200		
Power Supply							
Power Supply Range	V+			2.6		4.3	V
Power Supply Current	I+	V_{IN} = 0 V, or V+	Full			2	µA

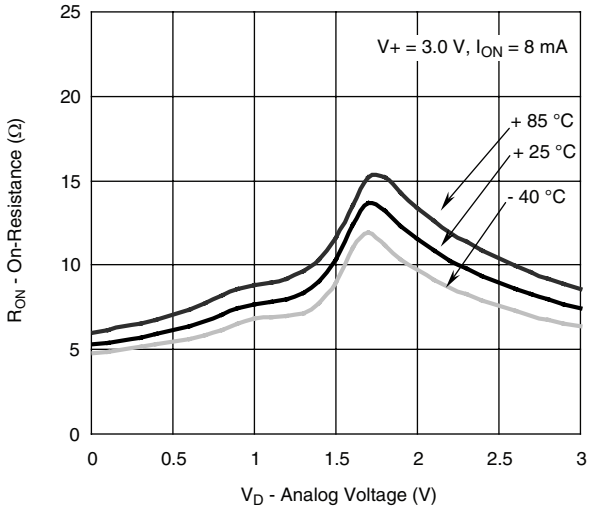
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, not subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

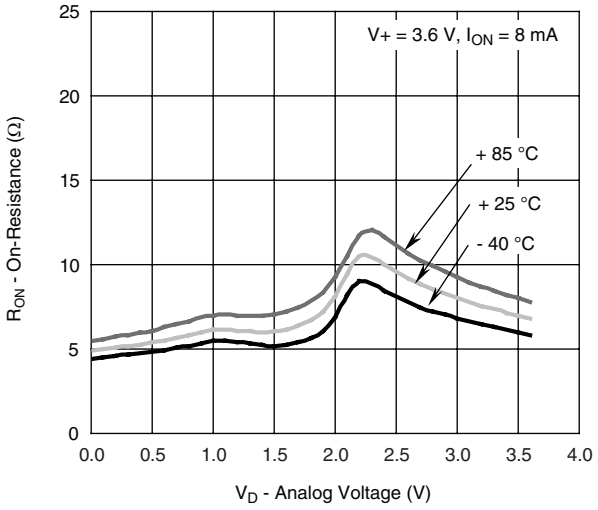
TYPICAL CHARACTERISTICS T_A = 25 °C, unless otherwise noted



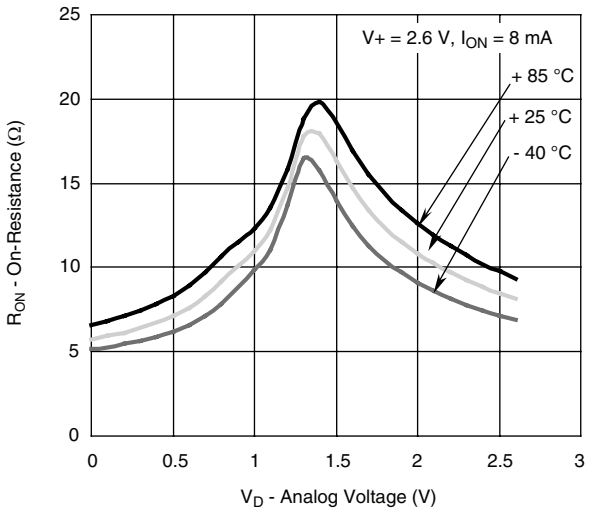
On-Resistance vs. V_D and Single Supply Voltage



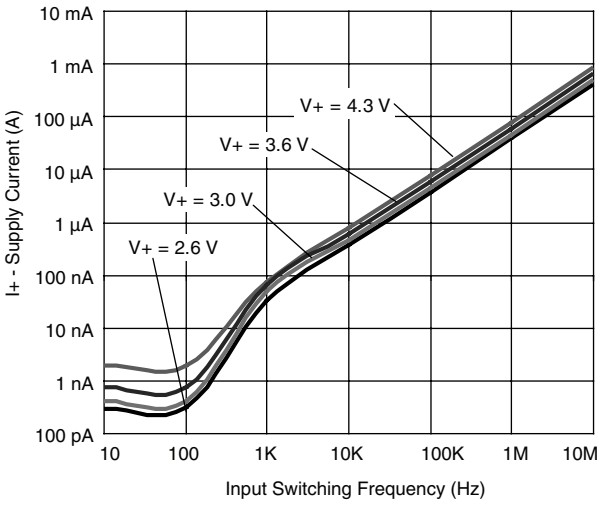
On-Resistance vs. Analog Voltage and Temperature



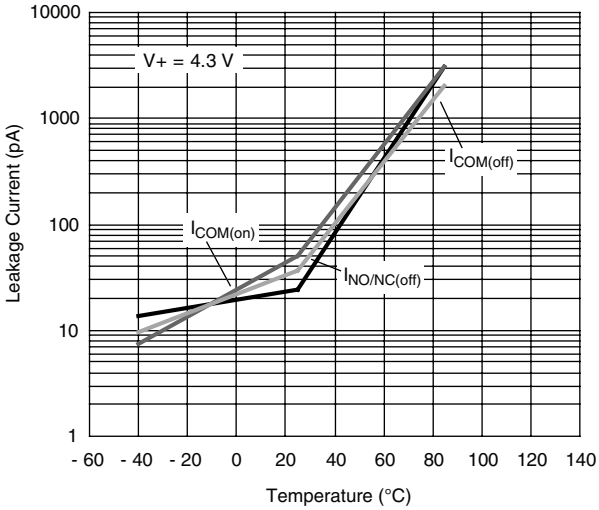
On-Resistance vs. Analog Voltage and Temperature



On-Resistance vs. Analog Voltage and Temperature

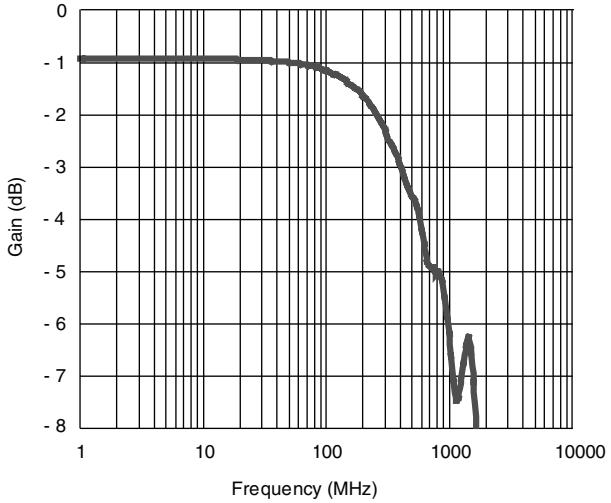


Supply Current vs. Input Switching Frequency

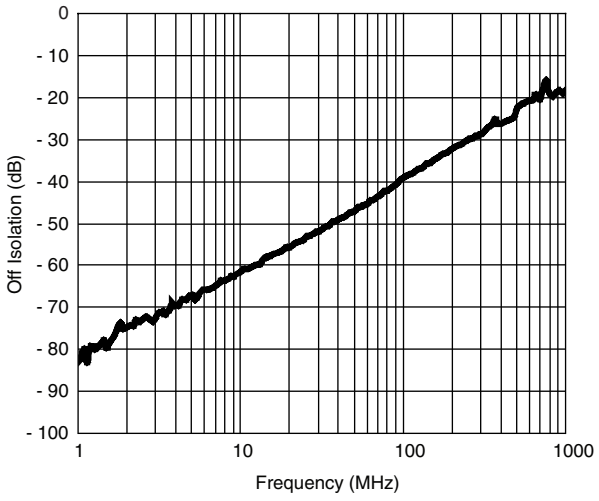


Leakage Current vs. Temperature

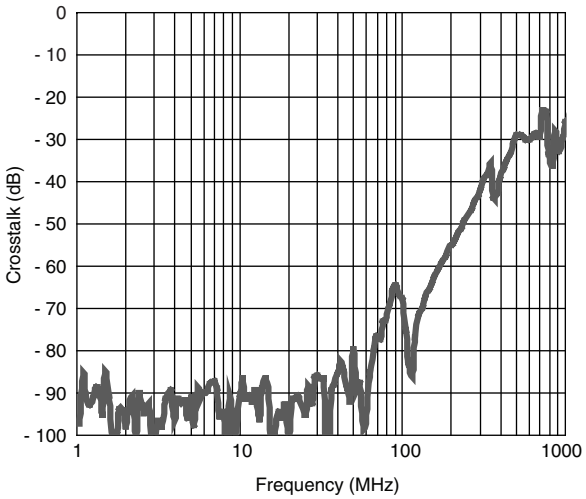
TYPICAL CHARACTERISTICS T_A = 25 °C, unless otherwise noted



Gain vs. Frequency, C_L = 5 pF, V+ = 3.3 V

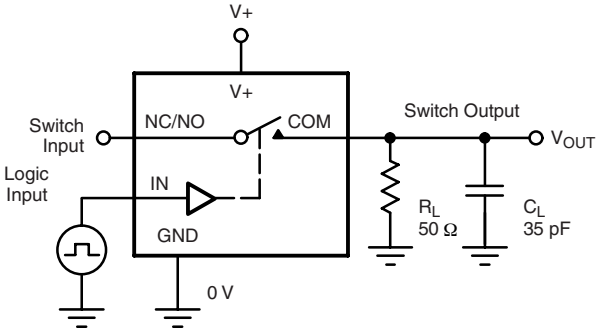


OFF Isolation, V+ = 3.3 V



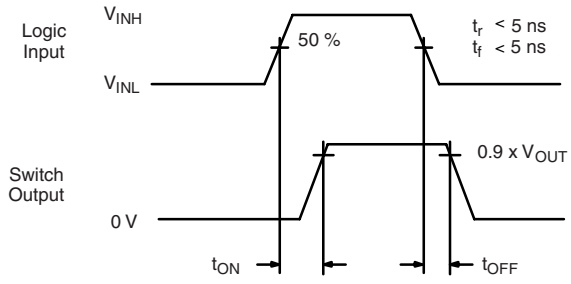
Crosstalk, V+ = 3.3 V

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

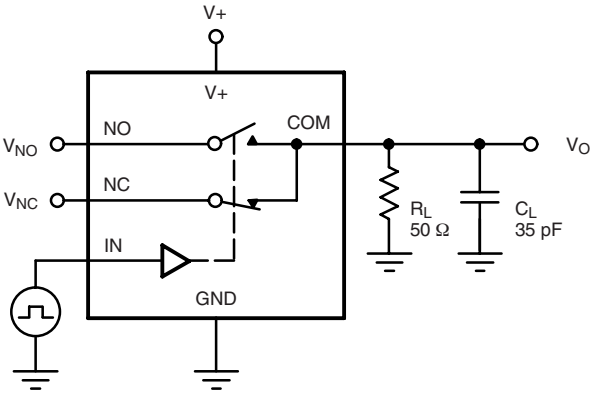
$$V_{OUT} = V_{COM}\left(\frac{R_L}{R_L + R_{ON}}\right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

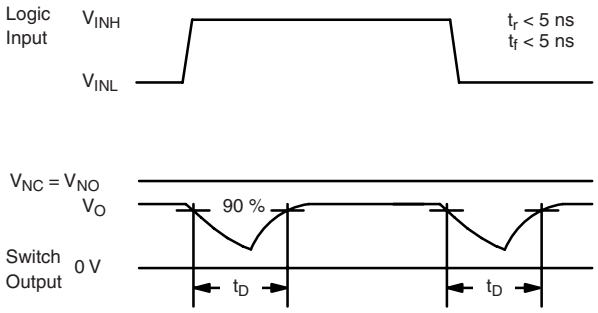
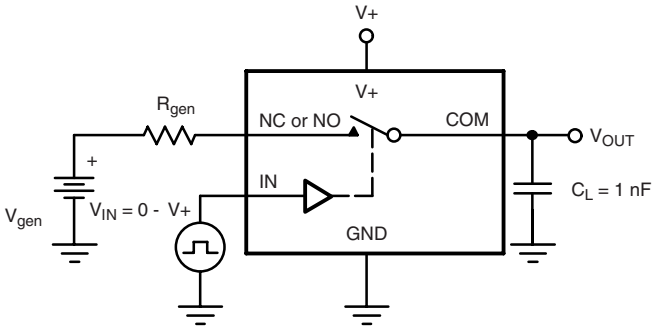
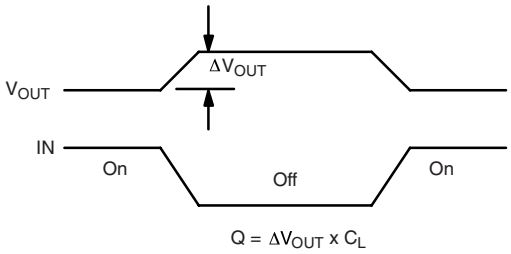


Figure 2. Break-Before-Make Interval





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

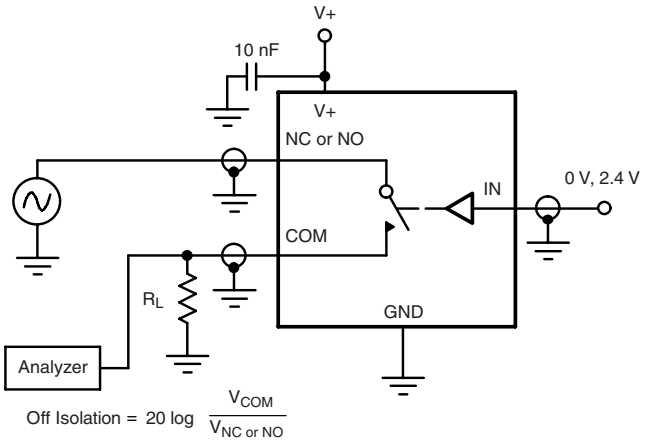


Figure 4. Off-Isolation

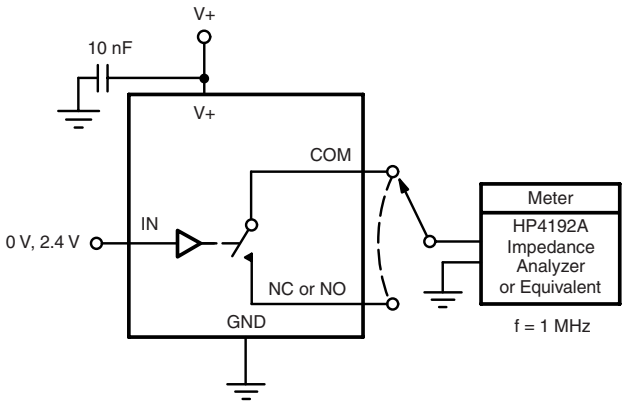


Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?69950.

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.